

## SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## FR151G THRU FR157G

# GLASS PASSIVATED FAST RECOVERY RECTIFIER

TECHNICAL SPECIFICATION

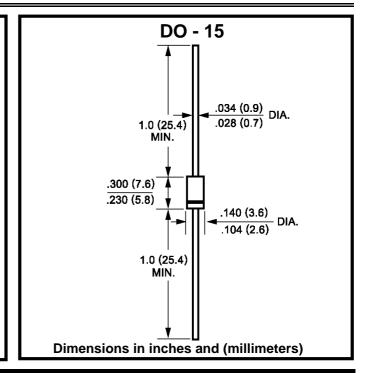
VOLTAGE: 50 TO 1000V CURRENT: 1.5A

#### **FEATURES**

- Molded case feature for auto insertion
- Glass passivated chip
- High current capability
- Low leakage current
- Fast switching for high efficiency
- High surge capability
- High temperature soldering guaranteed: 250°C/10sec/0.375"(9.5mm) lead length at 5 lbs tension

#### **MECHANICAL DATA**

- Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode
- Mounting position: Any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	FR	FR	FR	FR	FR	FR	FR	UNITS
			152G						
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		1.5							А
(9.5mm lead length, at T <sub>a</sub> =55°C)	I <sub>F(AV)</sub>								
Peak Forward Surge Current (8.3ms single		60.0							Α
half sine-wave superimposed on rated load)	I <sub>FSM</sub>								
Maximum Instantaneous Forward Voltage	$V_{F}$	1.3							V
(at rated forward current)	٧F								V
Maximum DC Reverse Current T <sub>a</sub> =25°C	5.0							μΑ	
(at rated DC blocking voltage) T <sub>a</sub> =100°C	l <sub>R</sub>	<sup>I</sup> R 100							μΑ
Maximum Reverse Recovery Time (Note 1)	trr	150 250 500				00	nS		
Typical Junction Capacitance (Note 2)	C <sub>J</sub>	20							pF
Typical Thermal Resistance (Note 3)	R <sub>θ</sub> (ja)	40							°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150							°C
Note:									

- 1.Reverse recovery condition I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, Irr=0.25A
- 2.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 3.Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C. board mounted